

LM2418 Triple 30 MHz CRT Driver

General Description

The LM2418 contains three large signal voltage amplifiers designed to directly drive CRT cathodes for VGA Color Graphics Displays. Output swings greater than 50 V_{PP} are achieved with a 90V power supply. The nominal voltage gain of each amplifier is 18 with gain matching of 1.0 dB between amplifiers.

Packaging is the industry standard molded 11 lead TO-220. The heatsink tab is isolated and may be grounded to improve RFI shielding and simplify assembly.

Features

- 50 V_{PP} output at 30 MHz drives CRT directly
- Rise/fall time typically 12 ns with 8 pF load
- 65V output swing capability
- Optimized output stage for low crossover distortion
- Gain matching of 1 dB
- Voltage gain of -19
- Includes oscillation suppression resistors

Applications

- CRT driver for RGB monitors
- High voltage amplifiers

Schematic and Connection Diagram

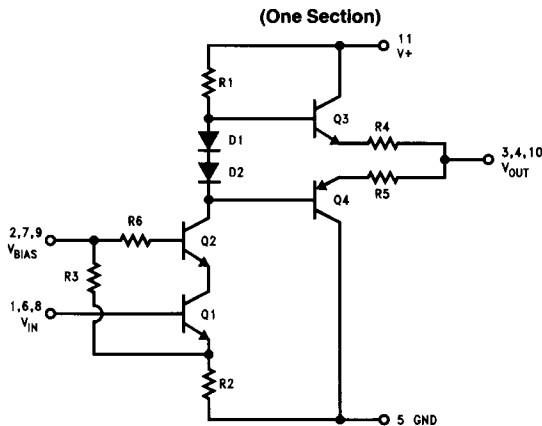
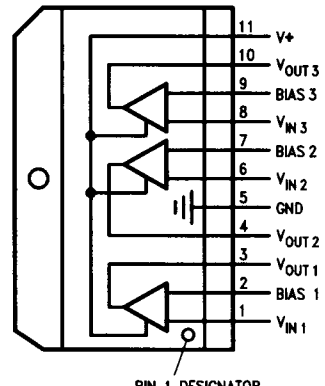


FIGURE 1



PIN 1 DESIGNATOR

TL/K/11125-2

TL/K/11125-1

Top View

Order Number LM2418T
See NS Package Number TA11B

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage, V^+ +95V

Storage Temperature Range, T_{STG} -25°C to +100°C

Operating Temperature Range, T_{CASE} -20°C to +100°C

Lead Temperature (Soldering, <10 sec.) 300°C

ESD Tolerance tbd

Electrical Characteristics

$V^+ = 90V$, $C_L = 8$ pF, DC input bias, $V_{IN} = 3.6$ V_{DC}, 50 V_{PP} output swing, $V_{BIAS} = +12V$, $T_A = 25^\circ C$ unless otherwise noted.

Symbol	Parameter	Conditions	LM2418			Units
			Min	Typ	Max	
I_{CC}	Supply Current (per Amplifier)	No Input or Output Load		18	26	mA
V_{OUT}	Output Offset Voltage	$V_{IN} = 3.6V$	46	53	60	V _{DC}
t_r	Rise Time	10% to 90% (Note 3)		12	20	ns
t_f	Fall Time	10% to 90% (Note 3)		12	20	ns
BW	Bandwidth	-3 dB		30		MHz
A_V	Voltage Gain		-17	-19	-23	V/V
OS	Overshoot			5		%
LE	Linearity Error	(Note 1)		8		%
ΔA_V	Gain Matching	(Note 2)		1.0		dB

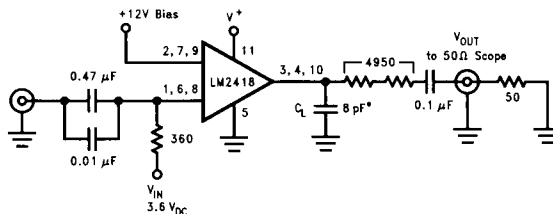
Note 1: Linearity Error is defined as the variation in small signal gain from +20V to +70V output with a 100 mV AC, 1 MHz, input signal.

Note 2: Calculated value from Voltage Gain test on each channel.

Note 3: Guaranteed parameter, not tested.

AC Test Circuit

Figure 2 shows a typical test circuit for evaluation of the LM2418. This circuit is designed to allow testing of the LM2418 in a 50Ω environment such as a pulse generator, oscilloscope or network analyzer.

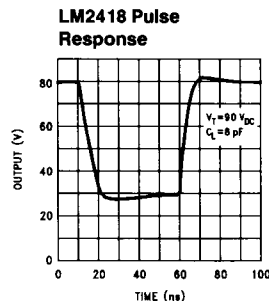
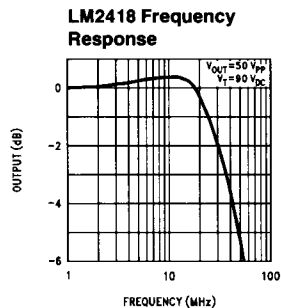


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*8 pF is total load capacitance. It includes all parasitic capacitance.

FIGURE 2. Test Circuit (One Section)

Typical Performance Characteristics



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FIGURE 3

TL/K/11125-5

LM2418—Theory of Operation

The LM2418 is a high voltage triple CRT driver suitable for VGA display applications. The LM2418 features 90V operation and low power dissipation. The part is housed in the industry standard 11-lead TO-220 molded power package. The heat sink is electrically isolated from the circuitry and may be grounded for ease of manufacturing and RFI shielding.

The circuit diagram of the LM2418 is shown in *Figure 1*. Q1 and R2 provide a conversion of input voltage to current, while Q2 acts as a common base or cascode amplifier stage to drive the load resistor R1. Emitter followers Q3 and Q4 isolate the impedance of R1 from the capacitance of the CRT cathode, and make the circuit relatively insensitive to load capacitance. The gain of this circuit is $-R1/R2$ and is fixed at -19 . The bandwidth of the circuit is set by the collector time constant formed by the load resistor R1 and associated capacitance of Q2, Q3, Q4, and stray layout capacitance. Diodes D1 and D2 provide forward bias to the output stage to reduce crossover distortion at low signal levels, while R3 provides a DC bias offset to match the output level characteristics of the LM1203 RGB Video Amplifier System. Proprietary transistor design allows for high bandwidth with low operating power.

Figure 2 shows a typical test circuit for evaluation of the LM2418. This circuit is designed to allow testing of the LM2418 in a 50 Ω environment such as a pulse generator and a scope, or a network analyzer. In this test circuit, two resistors in series totaling 4.95 k Ω form a wideband low

capacitance probe to match the output of the LM2418 to a 50 Ω cable and load. Typical AC performance of the circuit is shown in *Figure 3*. The input signal is AC coupled to the base of Q1, while a DC bias of 12V is applied to the base of Q2 (See *Figure 2*).

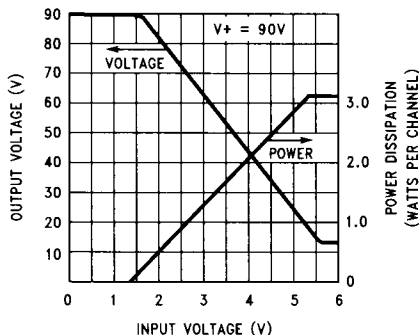
Thermal Considerations

The transfer characteristics of the amplifier are shown in *Figures 4* and *5*. Power supply current increases as the input signal increases and consequently power dissipation also increases.

The LM2418 cannot be used without heat sinking. *Figure 5* shows the power dissipated in each channel over the operating voltage range of the device. Typical "average" power dissipation with the device output voltage at one half the supply voltage is 1.8W per channel for a total dissipation of 5.4W package dissipation. Under white screen conditions, i.e., 20V output, dissipation increases to 3.0W per channel or 9W total. The LM2418 case temperature must be maintained below 100°C. If the maximum expected ambient temperature is 60°C, then a maximum heat sink thermal resistance can be calculated:

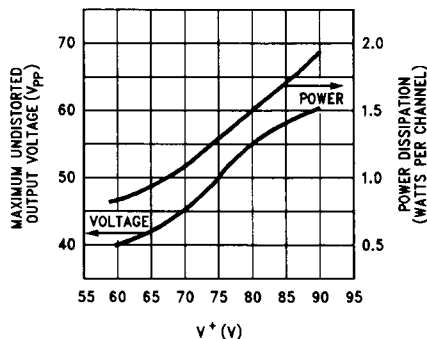
$$R_{th} = \frac{(100^{\circ}\text{C} - 60^{\circ}\text{C})}{9\text{W}} = 4.4^{\circ}\text{C/W}$$

PRECAUTION: THE LM2418 IS NOT PROTECTED AGAINST OUTPUT SHORT CIRCUITS. The minimum resistance the LM2418 can drive is 800 Ω to ground or V^{+} .



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FIGURE 4. LM2418 DC Characteristics



TL/K/11125-9

FIGURE 5. LM2418 Output Swing and Power Characteristics

Typical Application

A typical application of the LM2418 is shown in *Figure 6*. Used in conjunction with an LM1203, a complete video channel from monitor input to CRT cathode is shown. Performance is satisfactory for all applications up to 640 by 480 lines. Typical rise/fall times of this circuit are 15 ns, with

better than 50 V_{pp} drive signals available to a 10 pF load. In this application, feedback is local to the LM1203, an alternative scheme would feed back from the output of the LM2418 to the positive clamp inputs of the LM1203. This would provide better black level control of the system.

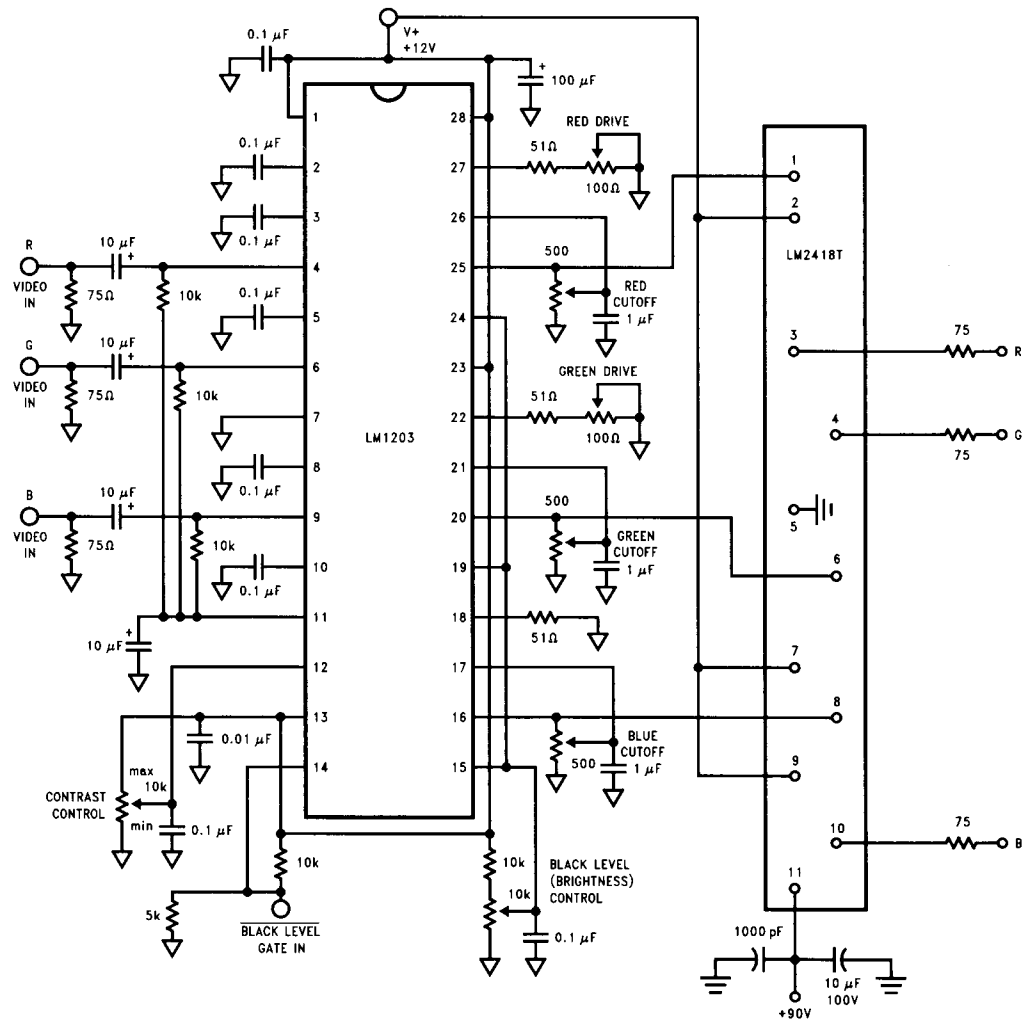
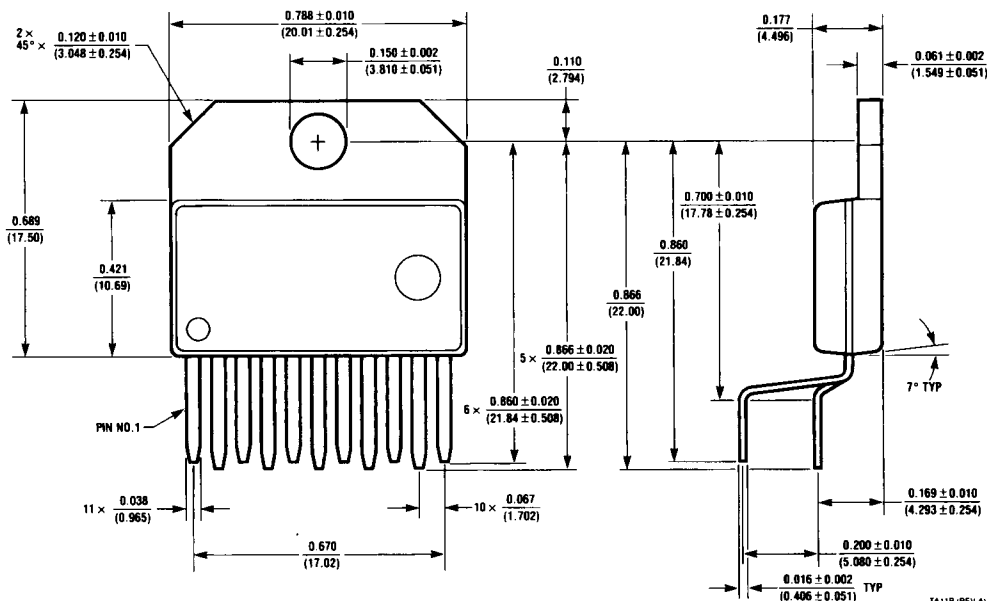


FIGURE 6. Typical Application LM1203-LM2418 Application

TL/K/11125-10



11 Lead TO-220 Molded Package (T)
Order Number LM2418T
NS Package Number TA11B

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